PTO/SB/08a Sheet 1 of 1' Atty. Docket No. Serial No. JAN 0 8 2009 2490-31 10/585,324 INFORMATION DISCLOSURE Applicant CITATION **DUNKLEY ET AL** (Use several sheets if necessary) Filing Date TC/A.U. September 26, 2006 2812

**U.S. PATENT DOCUMENTS** \*EXAMINER FILING DATE DOCUMENT NUMBER CLASS SUBCLASS IF APPROPRIATE INITIAL DATE NAME **FOREIGN PATENT DOCUMENTS** TRANSLATION DOCUMENT COUNTRY **CLASS SUBCLASS** YES NO DATE OTHER DOCUMENTS (including Author, Title, Date, Pertinent pages, etc.) Properties of Porous Silicon, edited by Leigh Canhan, DERA, Malvern, UK, Published by INSPEC, The Institution of /J.S./ Electrical Engineers, London, United Kingdom, ISBN 085296 932 5, Halimaoui, "1.2 Porous Silicon Formation by Anodisation", pages 12-19; 1997. 03/10/2010 /Jagadishwar Samala/ (03/10/2010) \*Examiner Date Considered

Examiner: Initial if reference considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.